GaAs-IR-Lumineszenzdiode GaAs Infrared Emitter

Lead (Pb) Free Product - RoHS Compliant

LD 274



Wesentliche Merkmale

- GaAs-LED mit sehr hohem Wirkungsgrad
- Hohe Zuverlässigkeit
- Gute spektrale Anpassung an Si-Fotoempfänger
- Gehäusegleich mit SFH 484

Anwendungen

- IR-Fernsteuerung von Fernseh- und Rundfunkgeräten, Videorecordern, Lichtdimmern
- Gerätefernsteuerungen für Gleich- und Wechsellichtbetrieb
- Sensorik
- Diskrete Lichtschranken

Features

- Very highly efficient GaAs-LED
- High reliability
- Spectral match with silicon photodetectors
- Same package as SFH 484

Applications

- IR remote control of hi-fi and TV-sets, video tape recorders, dimmers
- · Remote control for steady and varying intensity
- Sensor technology
- · Discrete interrupters

Typ Type	Bestellnummer Ordering Code	Gehäuse Package	
LD 274	Q62703Q1031	5-mm-LED-Gehäuse (T 1 ³ / ₄), graugetöntes Epoxy-	
LD 274-2 ¹⁾	Q62703Q1819	Gießharz, Anschlüsse im 2.54-mm-Raster (¹/10''), Kathodenkennzeichnung: Kürzerer Lötspieß, flat	
LD 274-3	Q62703Q1820	5 mm LED package (T 1 ³ / ₄), grey colored epoxy resin lens, solder tabs lead spacing 2.54 mm (¹ / ₁₀ "), cathode marking: shorter solder lead, flat	

¹⁾ Nur auf Anfrage lieferbar.



¹⁾ Available only on request.

Grenzwerte ($T_A = 25$ °C) **Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{ m op};T_{ m stg}$	- 40 + 100	°C
Sperrspannung Reverse voltage	V_{R}	5	V
Durchlassstrom Forward current	I_{F}	100	mA
Stoßstrom, $t_p = 10 \mu s$, $D = 0$ Surge current	I_{FSM}	3	А
Verlustleistung Power dissipation	P _{tot}	165	mW
Wärmewiderstand Thermal resistance	R_{thJA}	450	K/W

Kennwerte (T_A = 25 °C) **Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der Strahlung Wavelength at peak emission $I_{\rm F}$ = 100 mA, $t_{\rm p}$ = 20 ms	λ_{peak}	950	nm
Spektrale Bandbreite bei 50% von $I_{\rm max}$ Spectral bandwidth at 50% of $I_{\rm max}$ $I_{\rm F}$ = 100 mA, $t_{\rm p}$ = 20 ms	Δλ	55	nm
Abstrahlwinkel Half angle	φ	± 10	Grad
Aktive Chipfläche Active chip area	A	0.09	mm ²
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B \\ L \times W$	0.3 × 0.3	mm
Abstand Chipoberfläche bis Linsenscheitel Distance chip front to lens top	Н	4.9 5.5	mm
Schaltzeiten, $I_{\rm e}$ von 10% auf 90% und von 90% auf 10%, bei $I_{\rm F}$ = 100 mA, $R_{\rm L}$ = 50 Ω Switching times, $I_{\rm e}$ from 10% to 90% and from 90% to 10%, $I_{\rm F}$ = 100 mA, $R_{\rm L}$ = 50 Ω	t_{r},t_{f}	0.5	μs



Kennwerte (T_A = 25 °C) Characteristics (cont'd)

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit	
Kapazität Capacitance $V_{\rm R}$ = 0 V, f = 1 MHz	C_{o}	25	pF	
Durchlassspannung Forward voltage $I_{\rm F}$ = 100 mA, $t_{\rm p}$ = 20 ms $I_{\rm F}$ = 1 A, $t_{\rm p}$ = 100 μ s	$V_{F} \ V_{F}$	1.30 (≤ 1.5) 1.90 (≤ 2.5)	V V	
Sperrstrom, $V_R = 5 \text{ V}$ Reverse current	I_{R}	0.01 (≤ 1)	μΑ	
Gesamtstrahlungsfluss Total radiant flux $I_{\rm F}$ = 100 mA, $t_{\rm p}$ = 20 ms	Φ_{e}	15	mW	
Temperaturkoeffizient von $I_{\rm e}$ bzw. $\Phi_{\rm e}$, $I_{\rm F}$ = 100 mA Temperature coefficient of $I_{\rm e}$ or $\Phi_{\rm e}$, $I_{\rm F}$ = 100 mA	TC_1	- 0.55	%/K	
Temperaturkoeffizient von $V_{\rm F},I_{\rm F}$ = 100 mA Temperature coefficient of $V_{\rm F},I_{\rm F}$ = 100 mA	TC_{V}	- 1.5	mV/K	
Temperaturkoeffizient von λ , $I_{\rm F}$ = 100 mA Temperature coefficient of λ , $I_{\rm F}$ = 100 mA	TC_{λ}	+ 0.3	nm/K	



Gruppierung der Strahlstärke I_e in Achsrichtung

gemessen bei einem Raumwinkel Ω = 0.001 sr

Grouping of Radiant Intensity I_e in Axial Direction

at a solid angle of $\Omega = 0.001 \text{ sr}$

Bezeichnung Parameter	Symbol Symbol	Wert Value			Einheit Unit
		LD 274	LD 274-2 ¹⁾	LD 274-3	
Strahlstärke Radiant intensity $I_{\rm F}$ = 100 mA, $t_{\rm p}$ = 20 ms	$I_{\rm e \; min} \\ I_{\rm e \; max}$	50 -	50 100	80 –	mW/sr mW/sr
Strahlstärke Radiant intensity $I_{\rm F}$ = 1 A, $t_{\rm p}$ = 100 μ s	I _{e typ.}	350	600	800	mW/sr

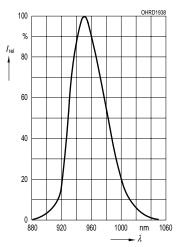
¹⁾ Nur auf Anfrage lieferbar.



¹⁾ Available only on request.

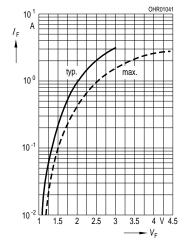
Relative Spectral Emission

 $I_{rel} = f(\lambda)$



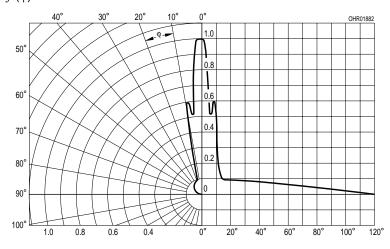
Forward Current

 $I_{\rm F} = f(V_{\rm F})$, single pulse, $t_{\rm p} = 20~\mu \rm s$



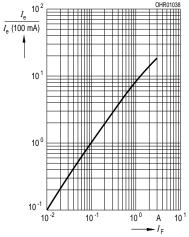
Radiation Characteristics,

 $I_{rel} = f(\varphi)$



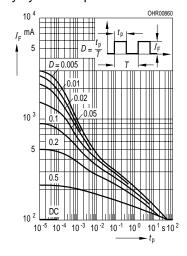
Radiant Intensity $\frac{I_{\rm e}}{I_{\rm e}\,$ 100 mA = $f(I_{\rm F})$

Single pulse, $t_p = 20 \mu s$

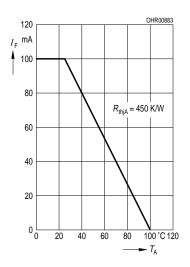


Permissible Pulse Handling Capability $I_F = f(\tau), T_C \le 25 \degree C$,

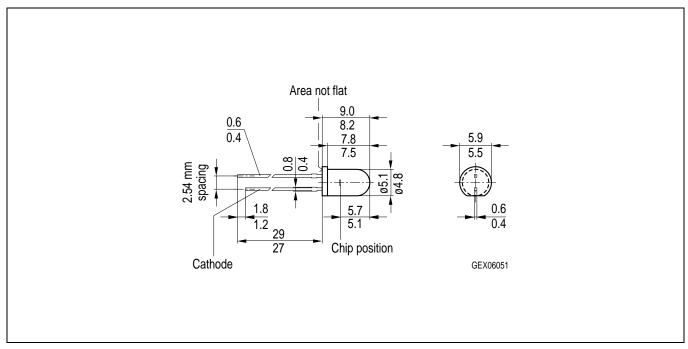
duty cycle D = parameter



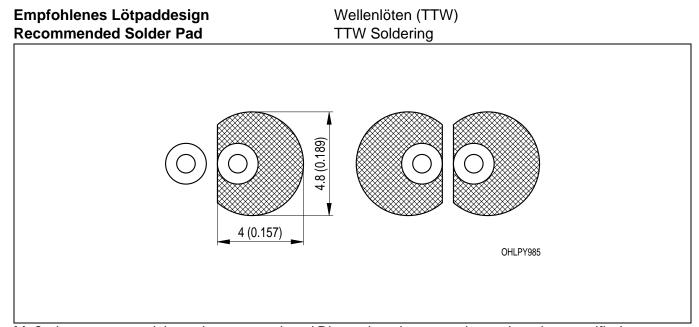
Max. Permissible Forward Current $I_{\mathsf{F}} = f(T_{\mathsf{A}})$



Maßzeichnung Package Outlines



Maße in mm, wenn nicht anders angegeben / Dimensions in mm, unless otherwise specified.

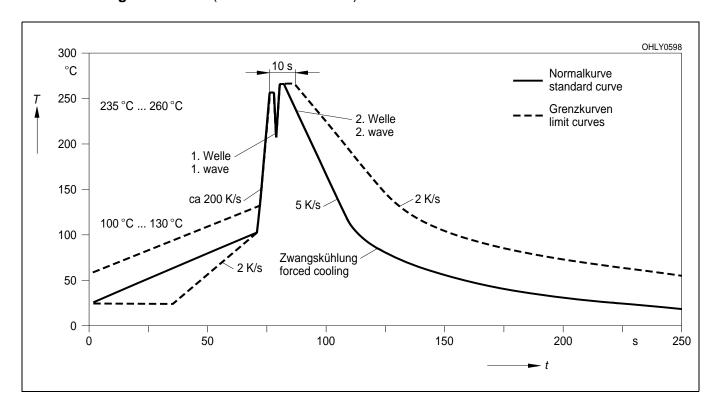


Maße in mm, wenn nicht anders angegeben / Dimensions in mm, unless otherwise specified.



Lötbedingungen Soldering Conditions Wellenlöten (TTW) TTW Soldering

(nach CECC 00802) (acc. to CECC 00802)



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